



# Silicon Variable Capacitance Diode

- For FM tuners
- Monolithic chip with common cathode for perfect tracking of both diodes
- Uniform "square law" characteristics
- Ideal HiFi tuning device when used in low-distortion, back-to-back configuration
- Pb-free (ROHS compliant) package



#### BB804

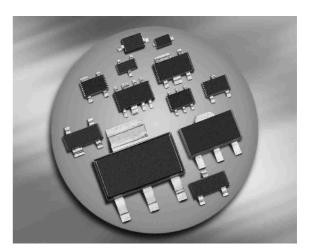


Туре	Package	Configuration	L <sub>S</sub> (nH)	Marking
BB804	SOT23	common cathode	1.8	SF1/2/3*

\*For differences see next page Capacitance groups

### **Maximum Ratings** at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit		
Diode reverse voltage	V <sub>R</sub>	18	V		
Peak reverse voltage	V <sub>RM</sub>	20			
Forward current	I <sub>F</sub>	50	mA		
Operating temperature range		-55 125	°C		
Storage temperature	T <sub>stg</sub>	-55 150			





Parameter	Symbol	Values			Unit
		min.	typ.	max.	1
DC Characteristics					
Reverse current	I <sub>R</sub>				nA
<i>V</i> <sub>R</sub> = 16 V		-	-	20	
<i>V</i> <sub>R</sub> = 16 V, <i>T</i> <sub>A</sub> = 65 °C		-	-	200	
AC Characteristics					
Diode capacitance <sup>1)</sup>	CT	42	-	47.5	pF
$V_{\rm R}$ = 2 V, <i>f</i> = 1 MHz					
Capacitance ratio	$C_{T2}/C_{T8}$	1.65	1.71	-	
$V_{\rm R}$ = 2 V, $V_{\rm R}$ = 8 V, $f$ = 1 MHz					
Series resistance	r <sub>S</sub>	-	0.18	-	Ω
V <sub>R</sub> = 2 V, <i>f</i> = 100 MHz					
Figure of merit	Q	-	200	-	
<i>f</i> = 100 MHz, <i>V</i> <sub>R</sub> = 2 V					
Temperature coefficient of diode capacitance	TCC	-	330	-	ppm/ł
$V_{R} = 2 V, f = 1 MHz$					
<sup>1</sup> Capacitance groups at 2V, coded 1; 2; 3			•		

# **Electrical Characteristics** at $T_A = 25^{\circ}$ C, unless otherwise specified

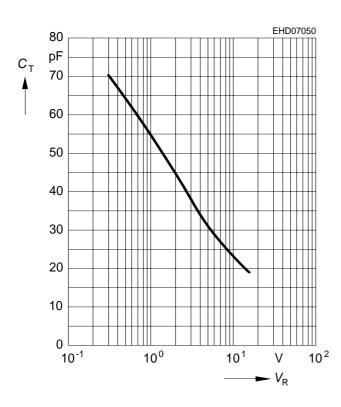
 $\begin{array}{cccc} ^{1} \text{ Capacitance groups at 2V}, \text{ coded 1; 2; 3} \\ C_{\text{T}}/\text{groups} & 1 & 2 & 3 \\ C_{\text{2V}} & \text{min} & 43\text{pF} & 44\text{pF} & 45\text{pF} \\ C_{\text{2V}} & \text{max} & 44.5\text{pF} & 45.5\text{pF} & 46.5\text{pF} \\ \end{array}$ 

The capacitance subgroup is marked by the subgroup number printed on the component and the package label. A packing unit (e.g. 8mm tape) contain diodes of one subgroup only. Delivery of different capacitance subgroups requires a special agreement.

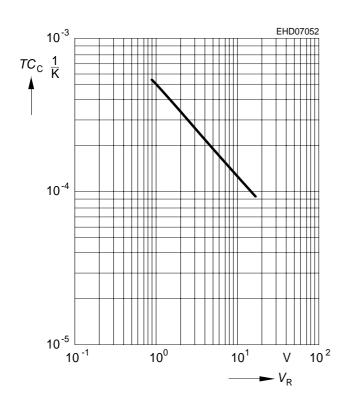


**Diode capacitance**  $C_{T} = f(V_{R})$ 

f = 1MHz

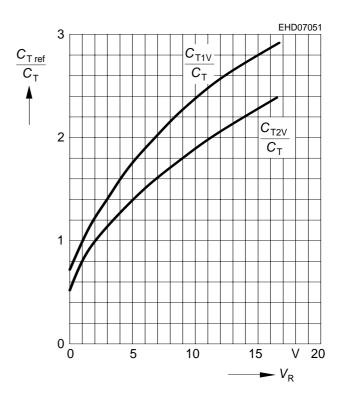


Temperatur coefficient  $TC_{C} = f(V_{R})$ 

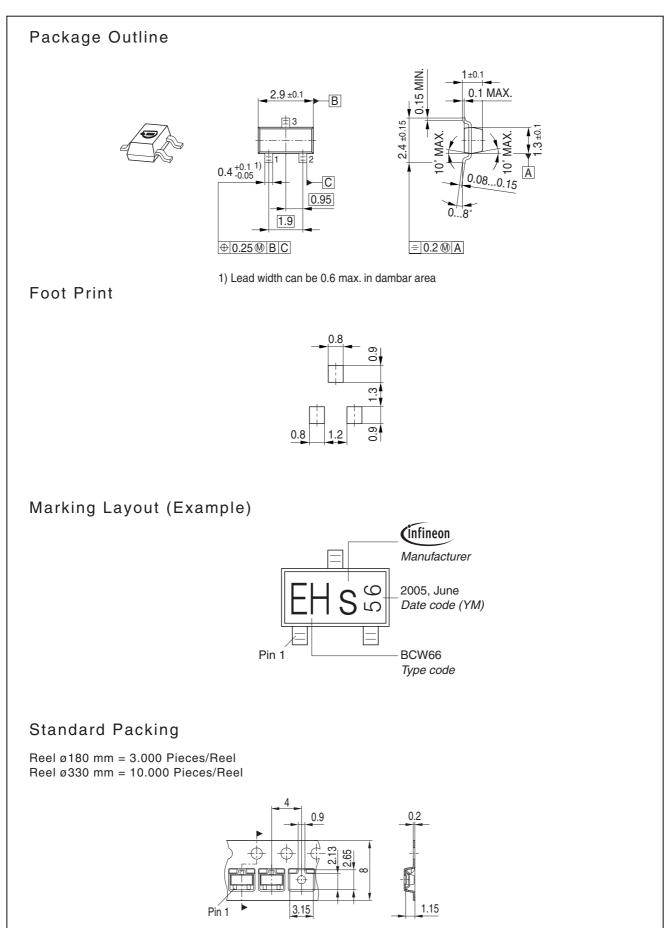


**Capacitance ratio**  $C_{\text{Tref}}/C_{\text{T}} = f(V_{\text{R}})$ 

f = 1 MHz









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